



Surface Mounted Power Resistor Thick Film Technology

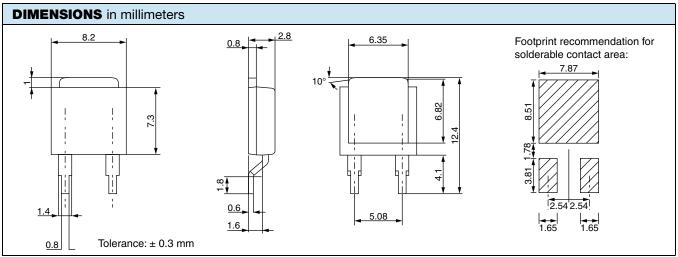


FEATURES

- AEC-Q200 qualified
- 25 W at 25 °C case temperature



- Wide resistance range: 0.016 Ω to 700 k Ω
- Non inductive
- · Resistor isolated from metal tab
- Solder reflow secure at 270 °C / 10 s, MSL = 1
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



Notes

- For the assembly, we recommend the lead (Pb)-free thermal profile as per J-STD-020C.
 Power dissipation is 3.2 W at an ambient temperature of 25 °C when mounted on a double sided copper board using FR4 HTG, 70 µm of copper, 39 mm x 30 mm x 1.6 mm, with thermal vias.
- For other information about dissipation, see the Application Note 52027: "Thermal Management on SMD Thick Film Resistors (D2TO20, D2TO35, DTO25)".

| STANDARD ELECTRICAL SPECIFICATIONS | | | | | | | |
|------------------------------------|---------------|---------------------------|-----------------------------------|---|------------------|--|-----------------------------|
| MODEL | SIZE | RESISTANCE RANGE Ω | RATED POWER P _{25 °C} W | LIMITING ELEMENT VOLTAGE U _L V | TOLERANCE ± % | TEMPERATURE COEFFICIENT ± ppm/°C | CRITICAL RESISTANCE Ω |
| DTO25 | TO-252 (DPAK) | 0.016 to 700K | 25 | 200 | 1, 2, 5, 10 | 150 | 1.6K |

| MECHANICAL SPECIFICATIONS | | | |
|---------------------------|-------------------------------|--|--|
| Mechanical Protection | Molded | | |
| Resistive Element | Thick film | | |
| Substrate | Alumina | | |
| Connections | Tinned copper, Ni under layer | | |
| Weight | 2 g max. | | |

| ENVIRONMENTAL SPECIFICATIONS | | | |
|------------------------------|--|--|--|
| Temperature Range | -55 °C to +150 °C | | |
| Climatic Category | 55 / 150 / 56 | | |
| | IEC 60695-11-5 | | |
| Flammability | 2 applications 30 s separated by 60 s | | |

| ELECTRICAL SPECIFICATIONS | | | | |
|-------------------------------------|--|--|--|--|
| Tolerances | From 0.016Ω to 0.047Ω : $\pm 5 \%$ and $\pm 10 \%$ $> 0.047 \Omega$ to 0.1Ω : $\pm 2 \%$ to $\pm 10 \%$ $\ge 0.1 \Omega$: $\pm 1 \%$ to $\pm 10 \%$ | | | |
| Power Rating and Thermal Resistance | 25 W at +25 °C case temperature R _{TH (j - c)} : 5 °C/W | | | |
| Temperature Coefficient | See Special Feature table ± 150 ppm/°C | | | |
| Dielectric Strength | 1500 V _{RMS} - 1 min - 15 mA max (between terminals and board) | | | |
| Insulation Resistance | $\geq 10^4 \ M\Omega$ | | | |
| Inductance | ≤ 0.1 µH | | | |

| DIMENSIONS | | | |
|------------------|---------------------|--|--|
| Standard Package | TO-252 style (DPAK) | | |



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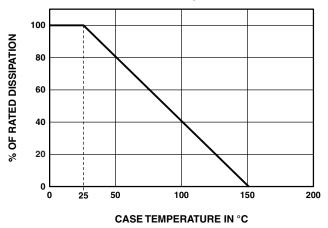
| SPECIAL FEATURES | | | | | |
|--|--------------|--------------|--------------|--|--|
| Resistance Values | ≥ 0.016 | ≥ 0.1 | ≥ 0.5 | | |
| Requirement Temperature Coefficient (TCR) (-55 °C +150 °C) IEC 60115-1 | ± 900 ppm/°C | ± 350 ppm/°C | ± 150 ppm/°C | | |

| PERFORMANCE | | | | |
|---------------------------|---|---------------------------------|--|--|
| TESTS | CONDITIONS | REQUIREMENTS | | |
| Momentary Overload | IEC 60115-1 §4.13 1.6 Pr 5 s US < 1.5 UL | ± (0.25 % + 0.005 Ω) | | |
| Load Life | IEC 60115-1 1000 h, 90/30 Pr at +25 °C | ± (1 % + 0.005 Ω) | | |
| High Temperature Exposure | AEC-Q200 REV D conditions: MIL-STD-202 method 108 1000 h, +175 °C, unpowered | ± (1 % + 0.005 Ω) | | |
| Temperature Cycling | AEC-Q200 REV D conditions: pre-conditioning 3 reflows according JESTD020D JESD22 method JA-104 1000 cycles, (-55 °C to +125 °C) dwell time 15 min | $\pm (0.5 \% + 0.005 \Omega)$ | | |
| Biased Humidity | AEC-Q200 REV D conditions: MIL-STD-202 method 103 1000 h, 85°C, 85 % RH | $\pm (0.5 \% + 0.005 \Omega)$ | | |
| Operational Life | AEC-Q200 REV D conditions: pre-conditioning 3 reflows according JESTD020D MIL-STD-202 method 108 1000 h, 90/30, powered, +125 °C | ± (1 % + 0.005 Ω) | | |
| ESD Human Body Model | AEC-Q200 REV D conditions: AEC-Q200-002 25 kV _{AD} | \pm (0.5 % + 0.005 Ω) | | |
| Vibration | AEC-Q200 REV D conditions: MIL-STD-202 method 204 5 g's for 20 min, 12 cycles test from 10 Hz to 2000 Hz | ± (0.5 % + 0.005 Ω) | | |
| Mechanical Shock | AEC-Q200 REV D conditions: MIL-STD-202 method 213 100 g's, 6 ms, 3.75 m/s 3 shocks/direction | ± (0.5 % + 0.005 Ω) | | |
| Board Flex | AEC-Q200 REV D conditions: AEC-Q200-005 bending 2 mm, 60 s | ± (0.25 % + 0.01 Ω) | | |
| Terminal Strength | AEC-Q200 REV D conditions: AEC-Q200-006 1.8 kgf, 60 s | ± (0.25 % + 0.01 Ω) | | |

| ASSEMBLY SPECIFICATIONS | | | | | |
|--------------------------------------|--|---|--|--|--|
| For the assembly on board, we recomm | For the assembly on board, we recommend the lead (Pb)-free thermal profile as per J-STD-020C | | | | |
| TESTS | CONDITIONS | REQUIREMENTS | | | |
| Resistance to Soldering Heat | AEC-Q200 REV D MIL-STD-202 method 210 Solder Bath method: 270 °C / 10 s | ± (0.5 % + 0.005 Ω) | | | |
| Moisture Sensitivity Level (MSL) | IPC / JEDEC J-STD-020C 85 °C / 85 % RH / 168 h | Level: 1 + pass requirements of TCR Overload and Dielectic Strength after MSL | | | |

POWER RATING

The temperature of the case should be maintained within the limits specified.



CHOICE OF THE BOARD

The user must choose the board according to the working conditions of the component (power, room temperature). Maximum working temperature must not exceed 150 °C. The dissipated power is simply calculated by the following ratio:

$$P \, = \, \frac{\Delta T}{R_{TH \, (j \, - \, c)} + R_{TH \, (c \, - \, h)} + R_{TH \, (h \, - \, a)}} (1)$$

P: Expressed in W

ΔΤ: Difference between maximum working temperature and room temperature

Thermal resistance value measured between resistive layer and outer side of the resistor. It is the thermal resistance R_{TH (j - c)}: of the component: 5 °C/W.

Thermal resistance value measured between outer side of the resistor and upper side of the board. This is the thermal resistance of the solder layer.

Thermal resistance of the board. $R_{TH (h - a)}$:

Example:

 $R_{TH~(c~-h)}$ + $R_{TH~(h~-a)}$ for DTO25 power rating 3 W at ambient temperature +25 °C.

Thermal resistance R_{TH (j - c)}: 5 °C/W

Considering equation (1) we have:

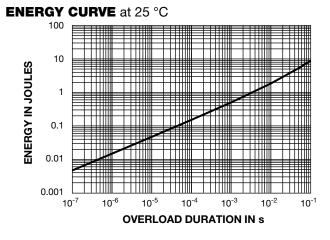
 $\Delta T = 150 \, ^{\circ}\text{C} - 25 \, ^{\circ}\text{C} = 125 \, ^{\circ}\text{C}$

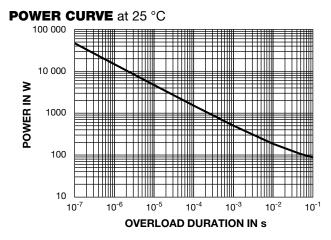
 $\begin{array}{l} R_{TH~(j~-c)} + R_{TH~(c~-h)} + R_{TH~(h~-a)} = \Delta T/P = 125/3 = 41.7~^{\circ}C/W \\ R_{TH~(c~-h)} + R_{TH~(h~-a)} = 41.7~^{\circ}C/W - 5~^{\circ}C/W = 36.7~^{\circ}C/W \end{array}$

ACCIDENTAL OVERLOAD

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In any case the applied voltage must be lower than the maximum overload voltage of U_s = 300 V. The values indicated on the graph below are applicable to resistors onto a board.





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Single Pulse:

These informations are for a single pulse on a cold resistor at 25 °C (not already used for a dissipation) and for pulses of 100 ms maximum duration.

The formula used to calculate E is:

$$E = P \times t = \frac{U^2}{R} \times t$$

with:

E (J): Pulse energy

P (W): Pulse power

t (s): Pulse duration

U (V): Pulse voltage

 $R(\Omega)$: Resistor

The energy calculated must be less than that allowed by the graph.

Repetitive or Superimposed Pulses:

The following formula is used to calculate the "equivalent" energy of a repetitive pulse or the "equivalent energy" of a pulse on a resistor that is already dissipating power.

$$E_{c} = E \times \left(1 + \frac{P_{a}}{P_{r}}\right)$$

with:

 E_c (J): Equivalent pulse energy

E (J): Known pulse energy

P_r: Resistor power rating

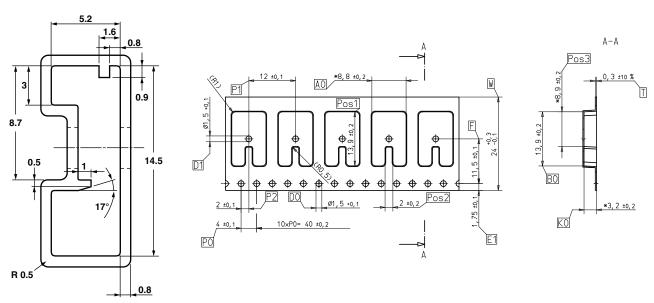
Pa: Mean power being dissipated

The energy calculated must be less than that allowed by the graph and the average power dissipated (P_a) must not exceed the continuous power of resistor.

PACKAGING

• Tube: max. 50 units per tube

• Reel: max. 500 units per reel



MARKING

Model, style, resistance value (in Ω), tolerance (in %), manufacturing date, Vishay Sfernice trademark.

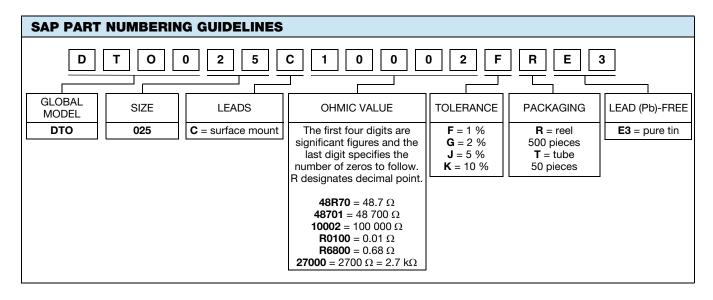




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| ORDERIN | G INFORM | ATION | | | | |
|---------|----------|-------------|---------------------|---|------------------------------------|----------------|
| DTO | 025 | С | 100 kΩ | ± 1 % | XXX | e3 |
| MODEL | STYLE | CONNECTIONS | RESISTANCE VALUE | TOLERANCE | CUSTOM DESIGN | LEAD (Pb)-FREE |
| | | | | $F = \pm 1 \%$ $G = \pm 2 \%$ $J = \pm 5 \%$ $K = \pm 10 \%$ | Optional on request: shape, etc | |





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